



## PNP SWITCHING SILICON TRANSISTOR

**Qualified per MIL-PRF-19500/290**

Qualified Levels:  
JAN, JANTX, JANTXV  
and JANS

### DESCRIPTION

This family of 2N2904AL and 2N2905AL switching transistors are military qualified up to the JANS level for high-reliability applications. These devices are also available in a TO-39 package. Microsemi also offers numerous other transistor products to meet higher and lower power ratings with various switching speed requirements in both through-hole and surface-mount packages.

**Important:** For the latest information, visit our website <http://www.microsemi.com>.

### FEATURES

- JEDEC registered 2N2904 through 2N2905 series.
- JAN, JANTX, JANTXV, and JANS qualifications are available per MIL-PRF-19500/290. (See [part nomenclature](#) for all available options.)
- RoHS compliant versions available (commercial grade only).

### APPLICATIONS / BENEFITS

- General purpose transistors for high speed switching applications.
- Military and other high-reliability applications.

### MAXIMUM RATINGS

| Parameters / Test Conditions                                                                                                          | Symbol              | Value       | Unit                 |
|---------------------------------------------------------------------------------------------------------------------------------------|---------------------|-------------|----------------------|
| Collector-Emitter Voltage                                                                                                             | $V_{CEO}$           | 60          | V                    |
| Collector-Base Voltage                                                                                                                | $V_{CBO}$           | 60          | V                    |
| Emitter-Base Voltage                                                                                                                  | $V_{EBO}$           | 5.0         | V                    |
| Thermal Resistance Junction-to-Ambient                                                                                                | $R_{\theta JA}$     | 195         | $^{\circ}\text{C/W}$ |
| Thermal Resistance Junction-to-Case                                                                                                   | $R_{\theta JC}$     | 50          | $^{\circ}\text{C/W}$ |
| Collector Current                                                                                                                     | $I_C$               | 600         | mA                   |
| Total Power Dissipation                                                                                                               | $P_T$               | 0.8         | W                    |
| <div>@ <math>T_A = +25^{\circ}\text{C}</math> <sup>(1)</sup></div> <div>@ <math>T_C = +25^{\circ}\text{C}</math> <sup>(2)</sup></div> |                     | 3.0         |                      |
| Operating & Storage Junction Temperature Range                                                                                        | $T_J$ and $T_{stg}$ | -65 to +200 | $^{\circ}\text{C}$   |

**Notes:** 1. For derating, see [figures 1 and 2](#).  
2. For thermal impedance, see [figures 3 and 4](#).



**TO-5 Package**

Also available in:

**TO-39 (TO-205AD) package**

(long-leaded)  
 [2N2904 & 2N2905A](#)

#### MSC – Lawrence

6 Lake Street,  
Lawrence, MA 01841  
Tel: 1-800-446-1158 or  
(978) 620-2600  
Fax: (978) 689-0803

#### MSC – Ireland

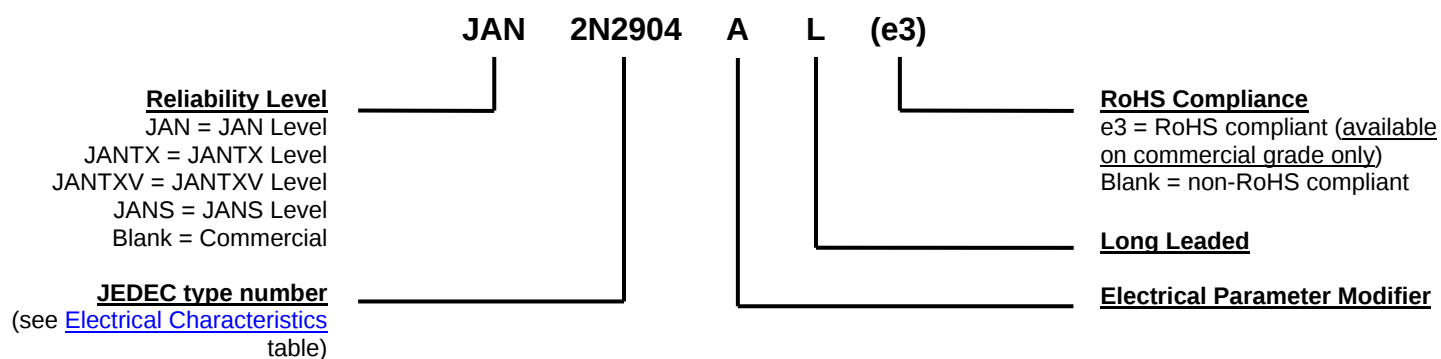
Gort Road Business Park,  
Ennis, Co. Clare, Ireland  
Tel: +353 (0) 65 6840044  
Fax: +353 (0) 65 6822298

**Website:**

[www.microsemi.com](http://www.microsemi.com)

**MECHANICAL and PACKAGING**

- CASE: Hermetically sealed, kovar base, nickel cap.
- TERMINALS: Tin/lead plate or RoHS compliant matte/tin (commercial grade only) over nickel.
- MARKING: Part number, date code, manufacturer's ID.
- POLARITY: PNP (see package outline).
- WEIGHT: Approximately 1.14 grams.
- See [Package Dimensions](#) on last page.

**PART NOMENCLATURE**

**SYMBOLS & DEFINITIONS**

| Symbol    | Definition                                                  |
|-----------|-------------------------------------------------------------|
| $C_{obo}$ | Common-base open-circuit output capacitance.                |
| $I_{CEO}$ | Collector cutoff current, base open.                        |
| $I_{CEX}$ | Collector cutoff current, circuit between base and emitter. |
| $I_{EBO}$ | Emitter cutoff current, collector open.                     |
| $h_{FE}$  | Common-emitter static forward current transfer ratio.       |
| $V_{CEO}$ | Collector-emitter voltage, base open.                       |
| $V_{CBO}$ | Collector-emitter voltage, emitter open.                    |
| $V_{EBO}$ | Emitter-base voltage, collector open.                       |

**ELECTRICAL CHARACTERISTICS @  $T_A = +25\text{ }^{\circ}\text{C}$ , unless otherwise noted**

| Parameters / Test Conditions                                                    | Symbol        | Min. | Max. | Unit          |
|---------------------------------------------------------------------------------|---------------|------|------|---------------|
| <b>OFF CHARACTERISTICS</b>                                                      |               |      |      |               |
| Collector-Emitter Breakdown Current<br>$I_C = 10\text{ mA}$                     | $V_{(BR)CEO}$ | 60   |      | V             |
| Collector-Emitter Cutoff Voltage<br>$V_{CE} = 60\text{ V}$                      | $I_{CES}$     |      | 1.0  | $\mu\text{A}$ |
| Collector-Base Cutoff Current<br>$V_{CB} = 60\text{ V}$ All Types               | $I_{CBO1}$    |      | 10   | $\mu\text{A}$ |
| $V_{CB} = 50\text{ V}$ 2N2904AL, 2N2905AL                                       | $I_{CBO2}$    |      | 10   | nA            |
| $V_{CB} = 50\text{ V @ } T_A = +150\text{ }^{\circ}\text{C}$ 2N2904AL, 2N2905AL | $I_{CBO3}$    |      | 10   | $\mu\text{A}$ |
| Collector-Base Cutoff Current<br>$V_{CB} = 50\text{ V}$                         | $I_{CBO}$     |      | 10   | nA            |
| $V_{CB} = 60\text{ V}$                                                          |               |      | 10   | $\mu\text{A}$ |
| Emitter-Base Cutoff Current<br>$V_{EB} = 3.5\text{ V}$                          | $I_{EBO}$     |      | 50   | nA            |
| $V_{EB} = 5.0\text{ V}$                                                         |               |      | 10   | $\mu\text{A}$ |

|                                                                                                                                |                      |          |           |                 |
|--------------------------------------------------------------------------------------------------------------------------------|----------------------|----------|-----------|-----------------|
| <b>ON CHARACTERISTICS <sup>(1)</sup></b>                                                                                       |                      |          |           |                 |
| Forward-Current Transfer Ratio<br>$I_C = 0.1\text{ mA}, V_{CE} = 10\text{ V}$                                                  | 2N2904AL<br>2N2905AL | $h_{FE}$ | 40<br>75  |                 |
| $I_C = 1.0\text{ mA}, V_{CE} = 10\text{ V}$                                                                                    | 2N2904AL<br>2N2905AL |          | 40<br>100 | 175<br>450      |
| $I_C = 10\text{ mA}, V_{CE} = 10\text{ V}$                                                                                     | 2N2904AL<br>2N2905AL |          | 40<br>100 |                 |
| $I_C = 150\text{ mA}, V_{CE} = 10\text{ V}$                                                                                    | 2N2904AL<br>2N2905AL |          | 40<br>100 | 120<br>300      |
| $I_C = 500\text{ mA}, V_{CE} = 10\text{ V}$                                                                                    | 2N2904AL<br>2N2905AL |          | 40<br>50  |                 |
| Collector-Emitter Saturation Voltage<br>$I_C = 150\text{ mA}, I_B = 15\text{ mA}$<br>$I_C = 500\text{ mA}, I_B = 50\text{ mA}$ | $V_{CE(sat)}$        |          |           | 0.4<br>1.6<br>V |
| Base-Emitter Saturation Voltage<br>$I_C = 150\text{ mA}, I_B = 15\text{ mA}$<br>$I_C = 500\text{ mA}, I_B = 50\text{ mA}$      | $V_{BE(sat)}$        |          |           | 1.3<br>2.6<br>V |

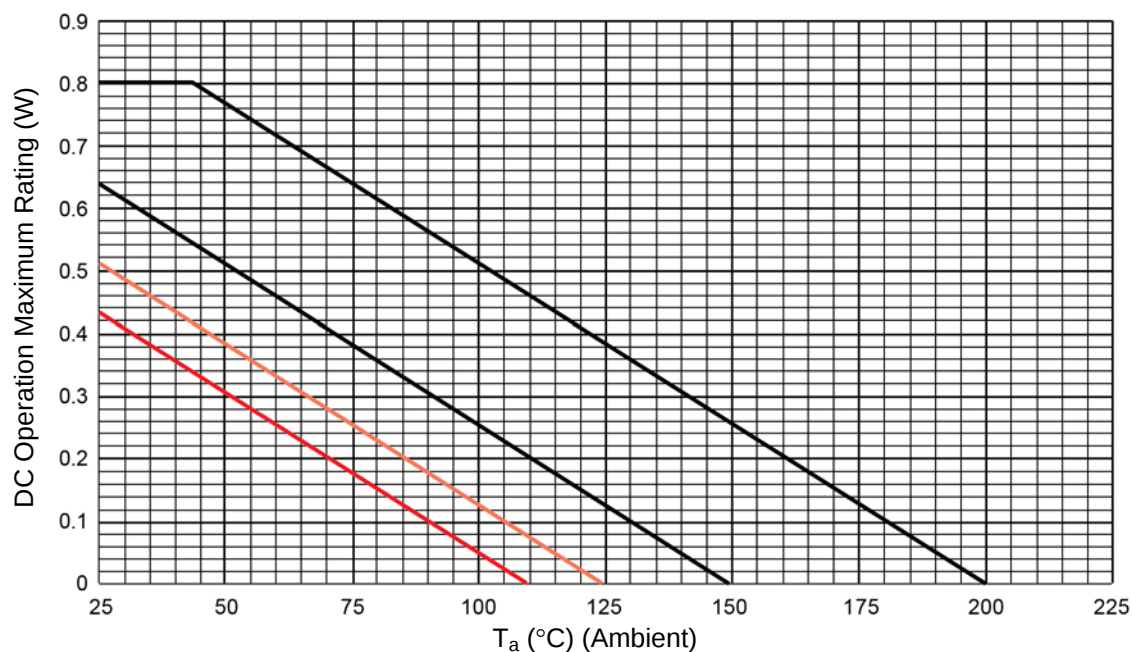
(1) Pulse Test: Pulse Width = 300  $\mu\text{s}$ , duty cycle  $\leq 2.0\%$ .

**ELECTRICAL CHARACTERISTICS @  $T_A = +25\text{ }^{\circ}\text{C}$ , unless otherwise noted (continued)****DYNAMIC CHARACTERISTICS**

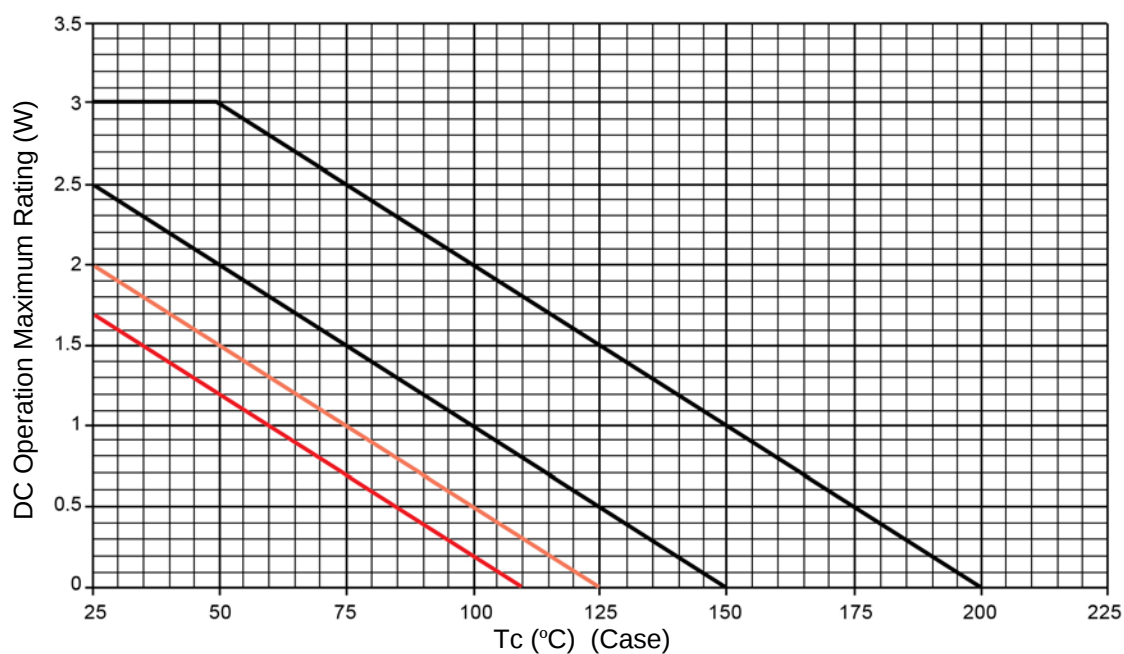
| Parameters / Test Conditions                                                                                                       | Symbol     | Min. | Max. | Unit |
|------------------------------------------------------------------------------------------------------------------------------------|------------|------|------|------|
| Small-Signal Short-Circuit Forward-Current Transfer Ratio<br>$I_C = 1.0\text{ mA}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ | $h_{fe}$   |      | 100  |      |
| Small-Signal Short-Circuit Forward-Current Transfer Ratio<br>$I_C = 50\text{ mA}$ , $V_{CE} = 20\text{ V}$ , $f = 100\text{ MHz}$  | $ h_{fe} $ |      | 2.0  |      |
| Output Capacitance<br>$V_{CB} = 10\text{ V}$ , $I_E = 0$ , $100\text{ kHz} \leq f \leq 1.0\text{ MHz}$                             | $C_{obo}$  |      | 8.0  | pF   |
| Input Capacitance<br>$V_{EB} = 2.0\text{ V}$ , $I_C = 0$ , $100\text{ kHz} \leq f \leq 1.0\text{ MHz}$                             | $C_{ibo}$  |      | 30   | pF   |

**SWITCHING CHARACTERISTICS**

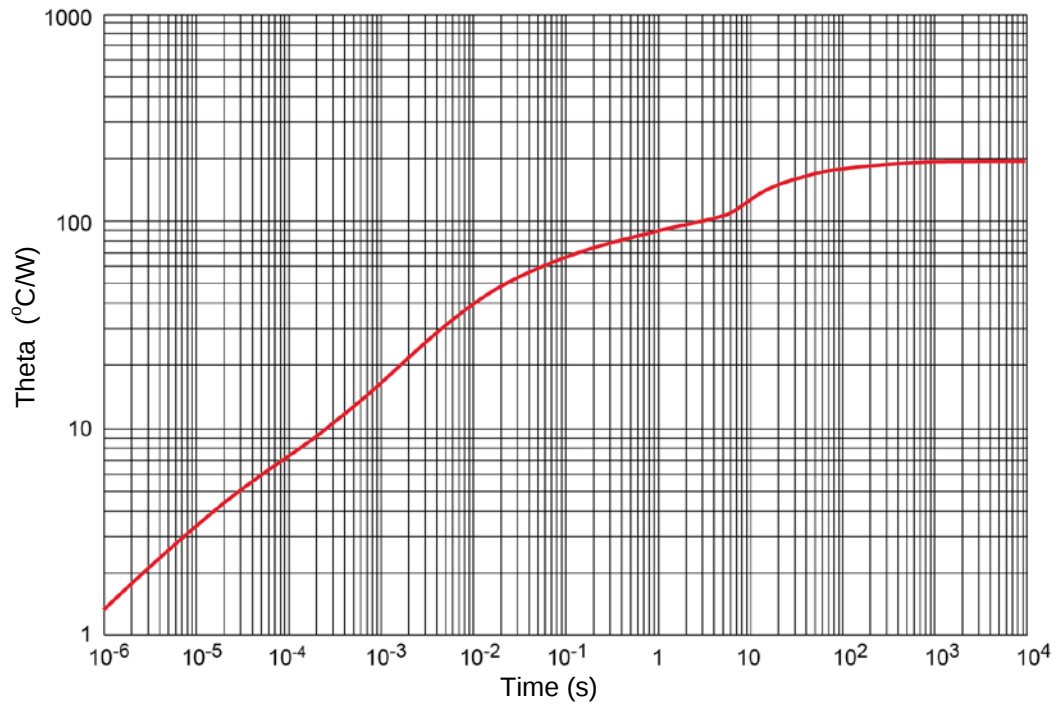
| Parameters / Test Conditions | Symbol    | Min. | Max. | Unit |
|------------------------------|-----------|------|------|------|
| Turn-On Time                 | $t_{on}$  |      | 45   | ns   |
| Turn-Off Time                | $t_{off}$ |      | 300  | ns   |

**GRAPHS**


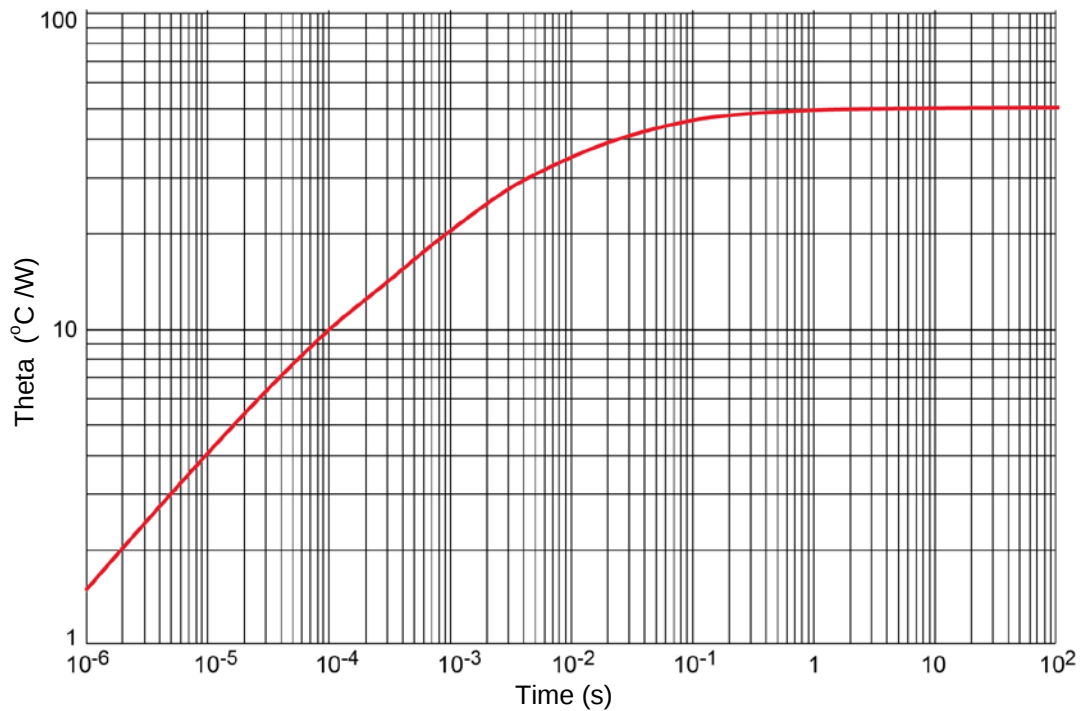
**FIGURE 1**  
Derating (R<sub>θJA</sub>) PCB



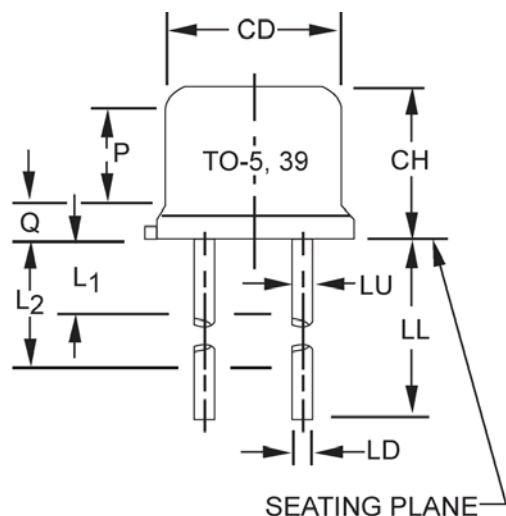
**FIGURE 2**  
Derating (R<sub>θJA</sub>) PCB

**GRAPHS (continued)**

**FIGURE 3**

Thermal impedance graph ( $R_{\theta JA}$ )


**FIGURE 4**

Thermal impedance graph ( $R_{\theta JA}$ )

**PACKAGE DIMENSIONS**


| Symbol | Dimensions |       |             |       | Note     |
|--------|------------|-------|-------------|-------|----------|
|        | Inch       |       | Millimeters |       |          |
|        | Min        | Max   | Min         | Max   |          |
| CD     | 0.305      | 0.335 | 7.75        | 8.51  |          |
| CH     | 0.240      | 0.260 | 6.10        | 6.60  |          |
| HD     | 0.335      | 0.370 | 8.51        | 9.40  |          |
| LC     | 0.200 TP   |       | 5.08 TP     |       | 6        |
| LD     | 0.016      | 0.021 | 0.41        | 0.53  | 7, 8     |
| LL     | 0.500      | 0.750 | 12.70       | 19.05 | 7, 8, 12 |
| LU     | 0.016      | 0.019 | 0.41        | 0.48  | 7, 8     |
| L1     |            | 0.050 |             | 1.27  | 7, 8     |
| L2     | 0.250      |       | 6.35        |       | 7, 8     |
| P      | 0.100      |       | 2.54        |       |          |
| Q      |            | 0.050 |             | 1.27  | 5        |
| TL     | 0.029      | 0.045 | 0.74        | 1.14  | 4        |
| TW     | 0.028      | 0.034 | 0.71        | 0.86  | 3        |
| r      |            | 0.010 |             | 0.25  | 10       |
| α      | 45° TP     |       | 45° TP      |       | 6        |

**NOTES:**

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. Beyond r (radius) maximum, TW shall be held for a minimum length of .011 (0.28 mm).
4. Dimension TL measured from maximum HD.
5. Body contour optional within zone defined by HD, CD, and Q.
6. Leads at gauge plane .054 +.001 -.000 inch (1.37 +0.03 -0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
7. Dimension LU applies between L1 and L2. Dimension LD applies between L2 and LL minimum. Diameter is uncontrolled in L1 and beyond LL minimum.
8. All three leads.
9. The collector shall be internally connected to the case.
10. Dimension r (radius) applies to both inside corners of tab.
11. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.
12. For "L" suffix devices, dimension LL is 1.50 (38.10 mm) minimum, 1.75 (44.45 mm) maximum.
13. Lead 1 = emitter, lead 2 = base, lead 3 = collector.

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